

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER OF PATENTS AND TRADEMARKS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

DATE MAILED: 05/08/2003

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/040,328	12/19/2001	Hiroshi Amano	10991002-4	3038
75	90 05/08/2003			•
AGILENT TECHNOLOGIES, INC. Legal Department, DL429 Intellectual Property Administration			EXAMINER	
			NGUYEN, DUNG T	
P.O. Box 7599 Loveland, CO	0537-0599		ART UNIT	PAPER NUMBER
20.0.0.0			2828	

Please find below and/or attached an Office communication concerning this application or proceeding.

. 1		Application No.	M/-
•			Applicant(s)
	Office Action Summary	10/040,328	AMANO ET AL.
	Office Action Summary	Examiner	Art Unit
	TI. MAILUIG DATE CO.	Dung (Michael) T Nguyen	2828
Period fo	The MAILING DATE of this communication a or Reply	opears on the cover sheet with the	e correspondence address
THE - Exte after - If the - If NC - Failu - Any	MAILING DATE OF THIS COMMUNICATION MAILING DATE OF THIS COMMUNICATION misions of time may be available under the provisions of 37 CFR 1 SIX (6) MONTHS from the mailing date of this communication. It is period for reply specified above is less than thirty (30) days, a reply period for reply is specified above, the maximum statutory period for reply within the set or extended period for reply will, by staturely received by the Office later than three months after the mailing date of the provided by the Office later than three months after the mailing date of the provided by the Office later than three months after the mailing date of the provided by the Office later than three months after the mailing date of the provided by the Office later than three months after the mailing date of the provided by the Office later than three months after the mailing date of this communication.	. 136(a). In no event, however, may a reply be ply within the statutory minimum of thirty (30) of d will apply and will expire SIX (6) MONTHS te. cause the application to become ARANDO	timely filed days will be considered timely. om the mailing date of this communication.
1)	Responsive to communication(s) filed on		
2a)□		his action is non-final.	
3)	Since this application is in condition for allow closed in accordance with the practice unde ion of Claims	vance except for formal matters,	prosecution as to the merits is , 453 O.G. 213.
4)⊠	Claim(s) 1-15 is/are pending in the application	on.	
	4a) Of the above claim(s) is/are withdra		
	Claim(s) is/are allowed.	ann nom concidentation.	Pault
·	Claim(s) <u>1-15</u> is/are rejected.		janop
	Claim(s) is/are objected to.		PAUL IP
	Claim(s) are subject to restriction and/	SUPERVIOR requirement TECH	ISORY PATENT EXAMINER NOLOGY CENTER 2800
	on Papers	i ologich rodanoment.	MOLOGI OLIVIZIONE
9) 🗌 -	The specification is objected to by the Examin	er.	
10)	The drawing(s) filed on is/are: a) ☐ acce	epted or b) objected to by the Ex	aminer.
	Applicant may not request that any objection to the	ne drawing(s) be held in abeyance.	See 37 CFR 1.85(a).
11) 🗌 -	The proposed drawing correction filed on	_ is: a)☐ approved b)☐ disapp	roved by the Examiner.
	If approved, corrected drawings are required in re	eply to this Office action.	
12) 🔲 🗆	Γhe oath or declaration is objected to by the Ε	xaminer.	
riority u	nder 35 U.S.C. §§ 119 and 120		
13)💢	Acknowledgment is made of a claim for foreign	n priority under 35 U.S.C. § 119	(a)-(d) or (f).
a)[X All b) Some * c) None of:		
	1. Certified copies of the priority documen	ts have been received.	
	2. Certified copies of the priority documen	ts have been received in Applica	ition No
	3. Copies of the certified copies of the price application from the International Boundary ee the attached detailed Office action for a list	ureau (PCT Rule 17.2(a)).	•
14) 🗌 A	cknowledgment is made of a claim for domes	ic priority under 35 U.S.C. § 119	(e) (to a provisional application)
a)	☐ The translation of the foreign language procknowledgment is made of a claim for domes	ovisional application has been re	eceived.
tachment	(s)		
) 🔲 Notice	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Information	ry (PTO-413) Paper No(s) I Patent Application (PTO-152)
Patent and Tra D-326 (Rev	ademark Office v. 04-01) Office A	ction Summary	Part of Paper No. 6

DETAILED ACTION

Drawings

The drawings are objected to under 37 CFR 1.83(a). The drawings must show every

feature of the invention specified in the claims. Therefore, the "substrate structure" (claim 7)

and the "gradient sub-layer" (claims 12-13) must be shown or the feature(s) canceled from the

claim(s). No new matter should be entered.

A proposed drawing correction or corrected drawings are required in reply to the Office

action to avoid abandonment of the application. The objection to the drawings will not be held

in abeyance.

Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the

subject matter which the applicant regards as his invention.

Claims 14-15 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for

failing to particularly point out and distinctly claim the subject matter which applicant regards as

the invention.

With respect to claim 14, it is not clear as what a portion of a nitride semiconductor layer

structure according to any one of the previous claims is included in the claim.

The remaining claim is dependent on the above rejected claim and therefore is also

rejected.

Art Unit: 2828

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1-11 and 14-15 are rejected under 35 U.S.C. 102(b) as being anticipated by Takeuchi et al. (US2001/0038656 based on Foreign Application Priority Data dated March 16, 1998).

With respect to claims 1-4, 10-11, and 14, Takeuchi show in Fig.8 a nitride semiconductor layer structure comprising a buffer layer 30, a first sub-layer 31, a second sub-layer 24 wherein the AlN molar fraction being at least 10% of the second sub-layer is greater than the AlN molar fraction being at least 5% of the first sub-layer (page 3, para.0033, l. 7-8, and para.0034, l. 1-3), an optical waveguide layer 25, an active layer 26, a first additional sub-layer 28, and a second additional sub-layer 33.

With respect to claim 5, Takeuchi disclose a sapphire substrate (page 1, para.0005, 1.10).

With respect to claim 6, Takeuchi disclose a SiC substrate (page 1, para.0005, 1.10).

With respect to claim 7, Takeuchi show in Fig.8 a substrate 21, a layer of GaN 23, and a layer 30 sandwiched between the substrate 21 and the layer of GaN 23.

Art Unit: 2828

With respect to claim 8, Takeuchi disclose the buffer layer and the composite layer are doped with the same dopant (page 3, para.0029, l. 1-2).

With respect to claim 9, Takeuchi disclose the buffer layer having a thickness less than 100nm, the buffer layer Al.sub y.Ga.sub 1-y.N (0 < y < 1), the composite layer Al.sub x.Ga.sub 1-x.N, and the second sub-layer is at least 600 nm (claim 16).

With respect to claim 15, Takeuchi disclose the second sub-layer has a thickness and the second AlN molar fraction has a value at which the laser generates light having a far field pattern that exhibits a single peak (page 3, para.0033).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 12-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Takeuchi et al. (US2001/0038656 based on Foreign Application Priority Data dated March 16, 1998) in view of Shieh et al. (US5530715). Takeuchi disclose all limitations of the claims except for a gradient layer. Shieh teach a gradient layer (Abstract, 1.4). For the benefit of a semiconductor layer

Application/Control Number: 10/040,328

Art Unit: 2828

structure, it would have been obvious to one having ordinary skill in the art at the time the

Page 5

invention was made to provide Takeuchi a gradient layer as taught by Shieh.

Citation of The Pertinent References

The following US patents are being made of record, even though they were not relied

upon in this Office action, for being similar in subject matter, and may be relied upon in any

future Office Actions: 6324200 and US2002/0137249.

Communication Information

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Dung (Michael) T Nguyen whose telephone number is (703) 305-

7159. The examiner can normally be reached on 8:30 - 17:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Paul Ip can be reached on (703) 308-3098. The fax phone numbers for the

organization where this application or proceeding is assigned are (703) 306-5511 for regular

communications and (703) 306-5511 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding

should be directed to the receptionist whose telephone number is (703) 306-3329.

Nguyen (Michael) Dung

April 21, 2003

TECHNOLOGY CENTER 2800